## NSN 5962-01-146-1849

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-146-1849 **Body Length:** 0.808 inches **Body Width:** 0.257 inches **Body Height:** 0.204 inches **Maximum Power Dissipation Rating:** 800.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and w/enable and 3-state output and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Gold Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

16 printed circuit

Shelf Life:

N/a

## NSN 5962-01-146-1849

Memory Microcircuit - Page 2 of 2



**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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